

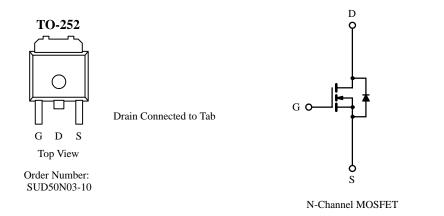
Siliconix

N-Channel 30-V (D-S), 175°C MOSFET

Product Summary

V _{DS} (V)	$\mathbf{r}_{\mathbf{DS(on)}}(\Omega)$	I _D (A)	
30	$0.010 @ V_{GS} = 10 V$	±15	
	$0.019 @ V_{GS} = 4.5 V$	±12	





Absolute Maximum Ratings ($T_A = 25^{\circ}C$ Unless Otherwise Noted)

Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	30		
Gate-Source Voltage		V _{GS}	± 20	V	
Continuous Drain Current ^a	$T_A=25^{\circ}C$	т	±15		
Continuous Drain Current.	$T_A = 100^{\circ}C$	I _D	± 10		
Pulsed Drain Current		I _{DM}	± 100	А	
Continuous Source Current (Diode Conduction) ^a		IS	15		
Maximum Douton Dissinction	$T_C = 25^{\circ}C$	р	83	W	
Maximum Power Dissipation	$T_A=25^\circ C$	P _D	4 ^a		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 175	°C	

Thermal Resistance Ratings

Parameter		Typical	Maximum	Unit
Maximum Junction-to-Ambient ^a	R _{thJA}		30	°C/W
Maximum Junction-to-Case	R _{thJC}		1.8	°C/W

Notes

a. Surface Mounted on FR4 Board, $t \leq 10$ sec.

Updates to this data sheet may be obtained via facsimile by calling Siliconix FaxBack, 1-408-970-5600. Please request FaxBack document #70265.

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Specifications ($T_J = 25^{\circ}C$ Unless Otherwise Noted)

Parameter	Symbol	Test Condition	Min	Typa	Max	Unit		
Static								
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I_D = 250 μA	30			v		
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS},I_D=250\;\mu A$	1.0	2.0				
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			±100	nA		
Zene Ceste Melte en Duein Comment	т	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$			1			
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} = 30 V, V_{GS} = 0 V, T_J = 125 $^\circ C$			50	μΑ		
On-State Drain Current ^b	I _{D(on)}	$V_{DS} = 5 V, V_{GS} = 10 V$	50			А		
		V_{GS} = 10 V, I_{D} =15 A			0.010			
Drain-Source On-State Resistance ^b	r _{DS(on)}	V_{GS} = 10 V, I_D =15 A, T_J = 125 °C			0.018	3 Ω		
		$V_{GS} = 4.5 \text{ V}, I_D = 15 \text{ A}$			0.019			
Forward Transconductance ^b	g _{fs}	$V_{DS} = 15 \text{ V}, I_D = 15 \text{ A}$	20			S		
Dynamic ^a			•					
Input Capacitance	C _{iss}			3200	6000	pF		
Output Capacitance	C _{oss}	V_{GS} = 0 V, V_{DS} = 25 V, F = 1 MHz		800				
Reverse Transfer Capacitance	C _{rss}			150				
Total Gate Charge ^c	Qg			55	100	nC		
Gate-Source Charge ^c	Qgs	$V_{DS} = 15 \text{ V}, \ V_{GS} = 10 \text{ V}, \ I_D = 50 \text{ A}$		10				
Gate-Drain Charge ^c	Qgd			9				
Turn-On Delay Time ^c	t _{d(on)}			16	30	ns		
Rise Time ^c	t _r	V_{DD} = 15 V, R_L = 0.3 Ω		8	20			
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong 50$ Å, $V_{GEN} = 10$ V, $R_G = 2.5 \Omega$		33	60			
Fall Time ^c	t _f			20	40			
Source-Drain Diode Ratings and C	haracteristic ($T_{C} = 25^{\circ}C)$	-	•	•	-		
Pulsed Current	I _{SM}				100	А		
Diode Forward Voltage ^b	V _{SD}	$I_F = 100 \text{ A}, V_{GS} = 0 \text{ V}$		1.2	1.5	V		
Blode I of Ward Voltage	55	1 65						

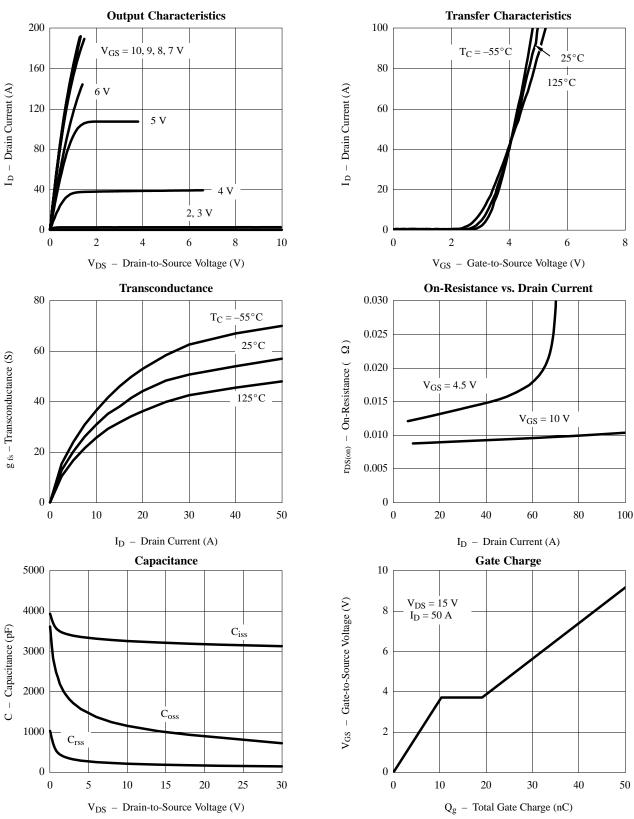
Notes

a. Guaranteed by design, not subject to production testing.

b. Pulse test; pulse width $\leq 300 \,\mu$ s, duty cycle $\leq 2\%$.

c. Independent of operating temperature.





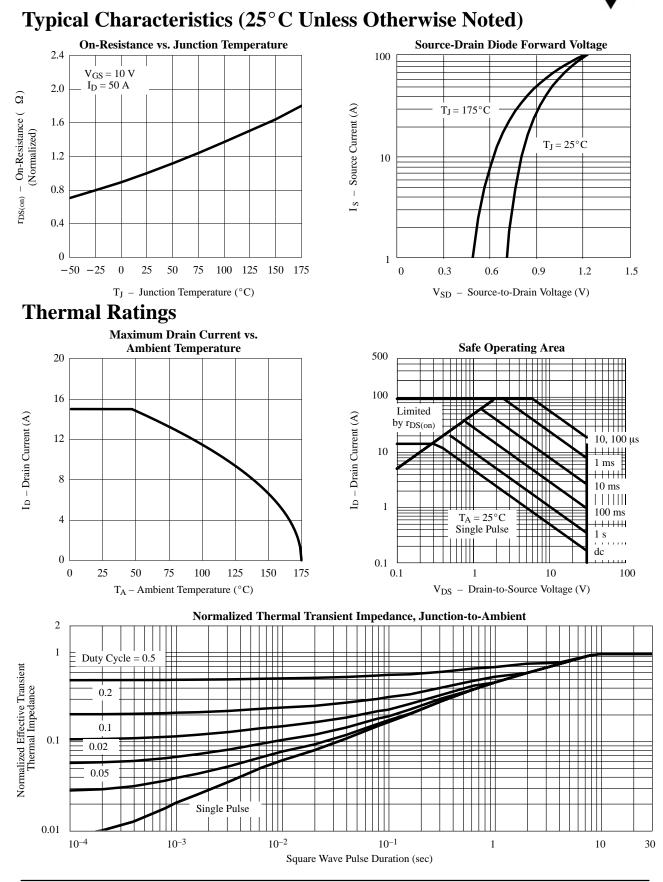
Typical Characteristics (25°C Unless Otherwise Noted)

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